

M.2 (S42)

3SE Series

Customer: _____

Customer

Part

Number: _____

Innodisk

Part

Number: _____

Innodisk

Model Name: _____

Date: _____

Innodisk Approver	Customer Approver

**Total Solution For
Industrial Flash Storage**

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REVISION HISTORY

Revision	Description	Date
Preliminary	First Released	May, 2014
1.0	Official release	June, 2014
1.1	Modify TBW based on NAND Flash specification	January, 2015

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1. Product Overview

1.1 Introduction of Innodisk M.2 (S42) 3SE

Innodisk M.2 (S42) 3SE is designed as the standard M.2 form factor with SATA interface, and supports SATA III standard (6.0Gb/s) with excellent performance. The form factor refers to the M.2(NGFF) specification which established by JEDEC. Regarding of mechanical interference, Innodisk M.2 (S42) 3SE absolutely replaces the traditional hard disk and makes personal computer, in any field, smaller and easier.

Innodisk M.2 (S42) 3SE effectively reduces the booting time of operation system and the power consumption is less than hard disk drive (HDD), and complies with ATA protocol, no additional drives are required, and can be configured as a boot device or data storage device

1.2 Product View and Models

Innodisk M.2 (S42) 3SE is available in follow capacities within SLC flash ICs.

[M.2 \(S42\) 3SE 04GB \(type 2242\)](#)

[M.2 \(S42\) 3SE 08GB \(type 2242\)](#)

[M.2 \(S42\) 3SE 16GB \(type 2242\)](#)

[M.2 \(S42\) 3SE 32GB \(type 2242\)](#)



Figure 1: Innodisk M.2 (S42) 3SE (type 2242)

1.3 SATA Interface

Innodisk M.2 (S42) 3SE supports SATA III interface, and compliant with SATA I and SATA II. SATA III interface can work with Serial Attached SCSI (SAS) host system, which is used in server computer. Innodisk M.2 (S42) 3SE is compliant with Serial ATA Gen 1, Gen 2 and Gen 3 specification (Gen 3 supports 1.5Gbps /3.0Gbps/6.0Gbps data rate).

2. Product Specifications

2.1 Capacity and Device Parameters

M.2 (S42) 3SE device parameters are shown in Table 1.

Table 1: Device parameters

Capacity	Cylinders	Heads	Sectors	LBA	user space
4GB	7773	16	63	7835184	3,825
8GB	15525	16	63	15649200	7,641
16GB	16383	16	63	31277232	15,272
32GB	16383	16	63	62533296	30,533

2.2 Performance

Burst Transfer Rate: 6.0Gbps

Table 2: Performance

Capacity	4GB	8GB	16GB	32GB
Sequential Read (max.)	220 MB/sec	250 MB/sec	290 MB/sec	290 MB/sec
Sequential Write (max.)	50 MB/sec	60 MB/sec	130 MB/sec	130 MB/sec

Note: the information is based on CrystalDiskMark 3.01 with file size 1000MB test patent

2.3 Electrical Specifications

2.3.1 Power Requirement

Table 3: Innodisk M.2 (S42) 3SE Power Requirement

Item	Symbol	Rating	Unit
Input voltage	V _{IN}	+3.3 DC +- 5%	V

2.3.2 Power Consumption

Table 4: Power Consumption

Mode	Power Consumption (mA)
Read	261 (max.)
Write	366 (max.)
Idle	125 (max.)

* Target: 32GB M.2 (S42) 3SE

2.4 Environmental Specifications

2.4.1 Temperature Ranges

Table 5: Temperature range for M.2 (S42) 3SE

Temperature	Range
Operating	Standard Grade: 0°C to +70°C
	Industrial Grade: -40°C to +85°C
Storage	-55°C to +95°C

2.4.2 Humidity

Relative Humidity: 10-95%, non-condensing

2.4.3 Shock and Vibration

Table 6: Shock/Vibration Testing for M.2 (S42) 3SE

Reliability	Test Conditions	Reference Standards
Vibration	7 Hz to 2K Hz, 20G, 3 axes	IEC 68-2-6
Mechanical Shock	Duration: 0.5ms, 1500 G, 3 axes	IEC 68-2-27

2.4.4 Mean Time between Failures (MTBF)

Table 7 summarizes the MTBF prediction results for various M.2 (S42) 3SE configurations. The analysis was performed using a RAM Commander™ failure rate prediction.

- **Failure Rate:** The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval under stated condition.
- **Mean Time between Failures (MTBF):** A basic measure of reliability for repairable items: The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

Table 7: M.2 (S42) 3SE MTBF

Product	Condition	MTBF (Hours)
Innodisk M.2 (S42) 3SE	Telcordia SR-332 GB, 25°C	>3,000,000

2.5 CE and FCC Compatibility

M.2 (S42) 3SE conforms to CE and FCC requirements.

2.6 RoHS Compliance

M.2 (S42) 3SE is fully compliant with RoHS directive.

2.7 Reliability

Parameter	Value
Read Cycles	Unlimited Read Cycles
Wear-Leveling Algorithm	Support
Bad Blocks Management	Support
Error Correct Code	Support
TBW	
4GB	216 (Sequential write)
8GB	432 (Sequential write)
16GB	864 (Sequential write)
32GB	1728 (Sequential write)

2.8 Transfer Mode

M.2 (S42) 3SE support following transfer mode:

Serial ATA III 6.0Gbps

Serial ATA II 3.0Gbps

Serial ATA I 1.5Gbps

2.9 Pin Assignment

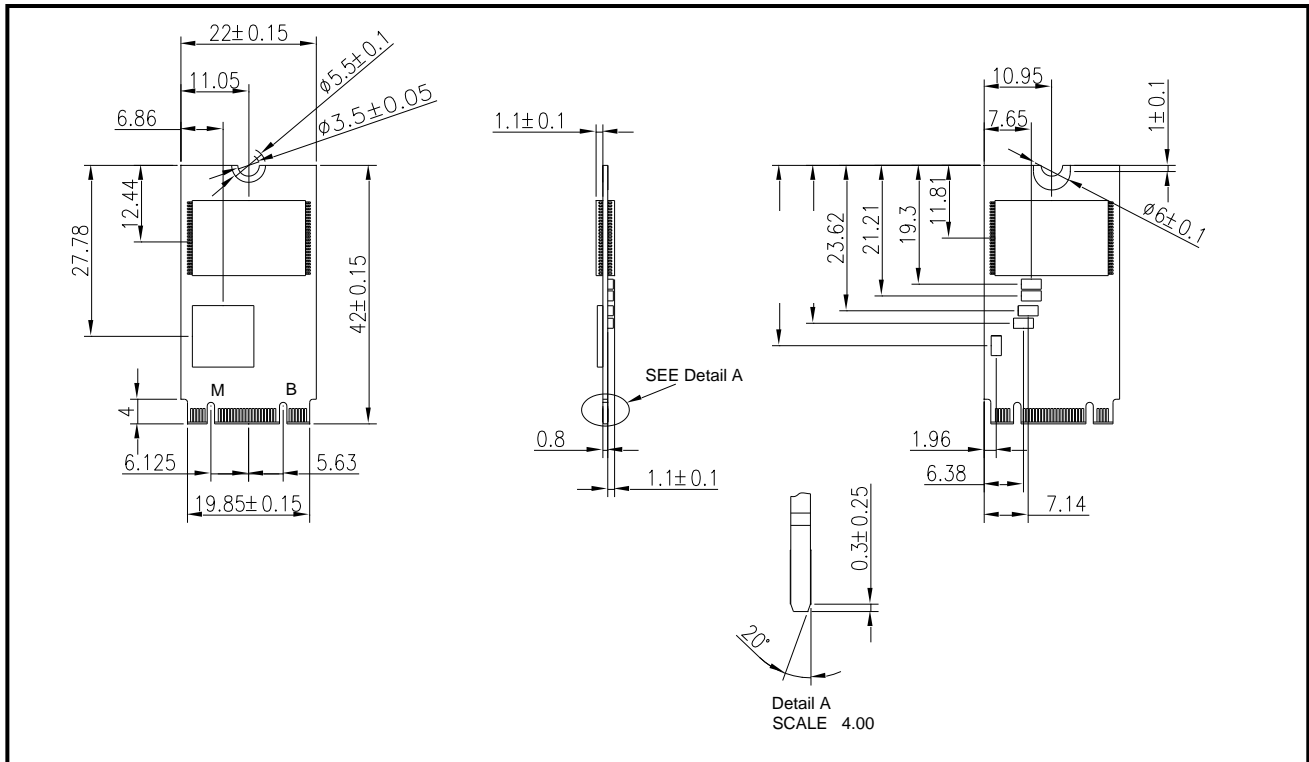
Innodisk M.2 (S42) 3SE uses a standard SATA pin-out. See Table 8 for M.2 (S42) 3SE pin assignment.

Table 8: Innodisk M.2 (S42) 3SE Pin Assignment

Signal Name	Pin #	Pin #	Signal Name
		75	GND
3.3V	74	73	GND
3.3V	72	71	GND
3.3V	70	69	GND
SUSCLK	68	67	NC
Notch	66	65	Notch
Notch	64	63	Notch
Notch	62	61	Notch
Notch	60	59	Notch
Reserved/ MFG Clock	58		
Reserved/ MFG Data	56	57	GND
NC	54	55	NC
NC	52	53	NC
NC	50	51	GND
NC	48	49	RX+
NC	46	47	RX-
NC	44	45	GND
NC	42	43	TX-
NC	40	41	TX+
DEVSLP	38	39	GND
NC	36	37	NC

NC	34	35	NC
NC	32	33	GND
NC	30	31	NC
NC	28	29	NC
NC	26	27	GND
NC	24	25	NC
NC	22	23	NC
NC	20	21	GND
Notch	18	19	Notch
Notch	16	17	Notch
Notch	14	15	Notch
Notch	12	13	Notch
DAS/DSS	10	11	NC
NC	8	9	NC
NC	6	7	NC
3.3V	4	5	NC
3.3V	2	3	GND
		1	GND

2.10 Mechanical Dimensions



2.11 Assembly Weight

An Innodisk M.2 (S42) 3SE within flash ICs, 32GB's weight is 8 grams approximately.

2.12 Seek Time

Innodisk M.2 (S42) 3SE is not a magnetic rotating design. There is no seek or rotational latency required.

2.13 Hot Plug

The SSD support hot plug function and can be removed or plugged-in during operation. User has to avoid hot plugging the SSD which is configured as boot device and installed operation system.

Surprise hot plug : The insertion of a SATA device into a backplane (combine signal and power) that has power present. The device powers up and initiates an OOB sequence.

Surprise hot removal: The removal of a SATA device from a powered backplane, without first being placed in a quiescent state.

2.14 NAND Flash Memory

Innodisk M.2 (S42) 3SE uses Single Level Cell (SLC) NAND flash memory, which is non-volatility, high reliability and high speed memory storage. There are only two statuses 0 or 1 of one cell. Read or Write data to flash memory for SSD is control by microprocessor.

3. Theory of Operation

3.1 Overview

Figure 2 shows the operation of Innodisk M.2 (S42) 3SE from the system level, including the major hardware blocks.

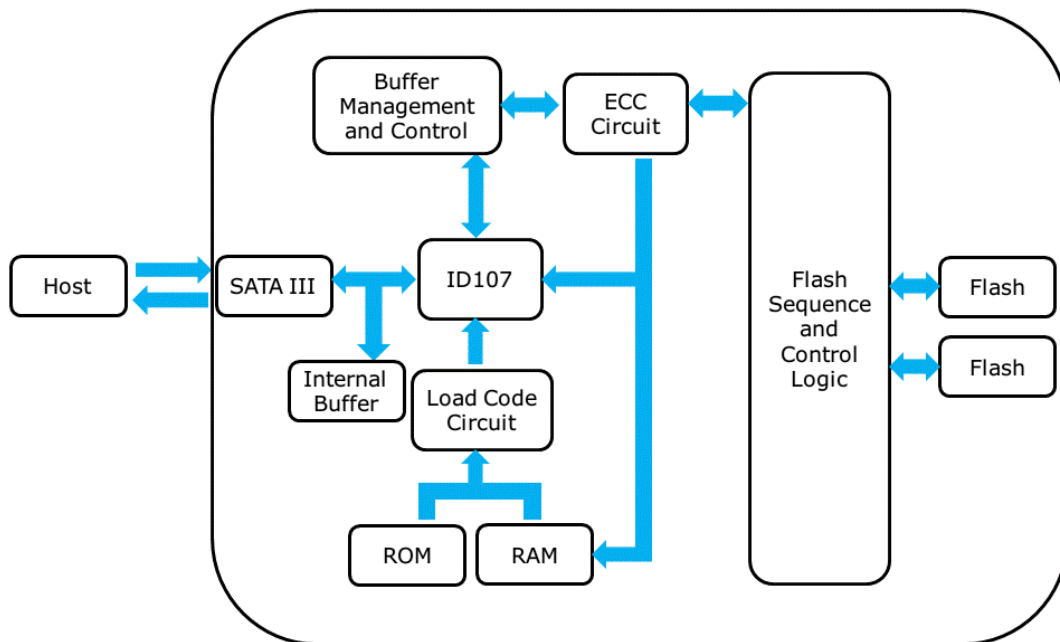


Figure 2: Innodisk M.2 (S42) 3SE Block Diagram

Innodisk M.2 (S42) 3SE integrates a SATA III controller and NAND flash memories. Communication with the host occurs through the host interface, using the standard ATA protocol. Communication with the flash device(s) occurs through the flash interface.

3.2 SATA III Controller

Innodisk M.2 (S42) 3SE is designed with ID 107, a SATA III 6.0Gbps (Gen. 3) controller. The Serial ATA physical, link and transport layers are compliant with Serial ATA Gen 1, Gen 2 and Gen 3 specification (Gen 3 supports 1.5Gbps/3.0Gbps/6.0Gbps data rate). The controller has 2 channels for flash interface.

3.3 Error Detection and Correction

Highly sophisticated Error Correction Code algorithms are implemented. The ECC unit consists of the Parity Unit (parity-byte generation) and the Syndrome Unit (syndrome-byte computation). This unit implements an algorithm that can correct 40 bits per 1024 bytes in an ECC block. Code-byte generation during write operations, as well as error detection during read operation, is implemented on the fly without any speed penalties.

3.4 Wear-Leveling

Flash memory can be erased within a limited number of times. This number is called the **erase cycle limit** or **write endurance limit** and is defined by the flash array vendor. The erase cycle limit applies to each individual erase block in the flash device.

Innodisk M.2 (S42) 3SE uses a static wear-leveling algorithm to ensure that consecutive writes of a specific sector are not written physically to the same page/block in the flash. This spreads flash media usage evenly across all pages, thereby extending flash lifetime.

3.5 Bad Blocks Management

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the SSD is shipped, or may develop during the life time of the SSD. When the Bad Blocks is detected, it will be flagged, and not be used anymore. The SSD implement Bad Blocks management, Bad Blocks replacement, Error Correct Code to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit.

3.6 Power Cycling

Innodisk's power cycling management is a comprehensive data protection mechanism that functions before and after a sudden power outage to SSD. Low-power detection terminates data writing before an abnormal power-off, while table-remapping after power-on deletes corrupt data and maintains data integrity. Innodisk's power cycling provides effective power cycling management, preventing data stored in flash from degrading with use.

3.7 Garbage Collection

Garbage collection is used to maintain data consistency and perform continual data cleansing on SSDs. It runs as a background process, freeing up valuable controller resources while sorting good data into available blocks, and deleting bad blocks. It also significantly reduces write operations to the drive, thereby increasing the SSD's speed and lifespan.

4. Installation Requirements

4.1 M.2 (S42) 3SE Pin Directions

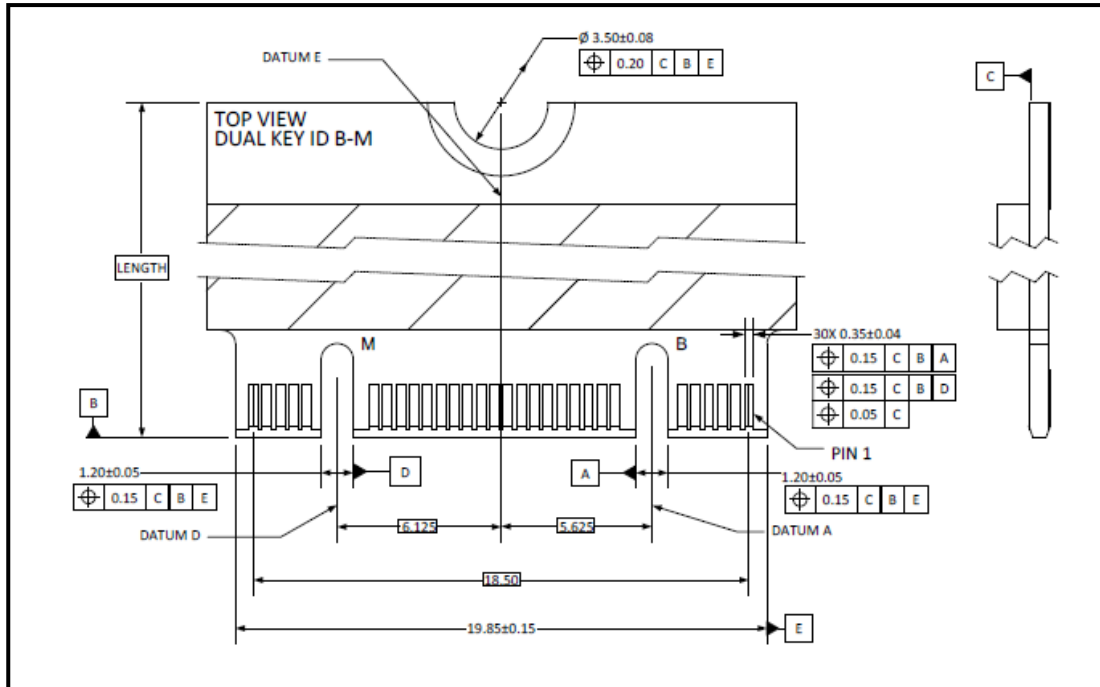


Figure 3: Signal Segment and Power Segment

4.2 Electrical Connections for M.2 (S42) 3SE

A Serial ATA device may be either directly connected to a host or connected to a host through a cable. For connection via cable, the cable should be no longer than 1meter. The SATA interface has a separate connector for the power supply. Please refer to the pin description for further details.

4.3 Device Drive

No additional device drives are required. The Innodisk M.2 (S42) 3SE can be configured as a boot device.

5. Part Number Rule

CODE	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21
	D	E	M	2	4	-	3	2	G	D	0	7	S	C	A	D	B	-	X	X	X
Definition																					
Code 1st (Disk)											Code 14th (Operation Temperature)										
D : Disk											C: Standard Grade (0°C ~ +70°C)										
											W: Industrial Grade (-40°C ~ +85°C)										
Code 2nd ~5th (Form factor)											Code 15th (Internal control)										
EM24: M.2-SATA Type 2242											A: BGA PCB version.										
Code 7th ~9th (Capacity)											Code 16th (Channel of data transfer)										
04G: 4GB											D: Dual Channels										
08G: 8GB																					
16G: 16GB.																					
32G: 32GB																					
Code 10th ~12th (Controller)											Code 17th (Flash Type)										
D07: ID107											B: Toshiba SLC										
Code 13th (Flash mode)											Code 19th~21st (Customize code)										
S: Synchronous NAND.																					

Certificate

Issue Date: May 14, 2014
 Ref. Report No. ISL-14LE187CE

Product Name : M.2 (S42) 3SE; M.2 (S42) 3ME; M.2 (S42) 3IE
 Model(s) : DEM24-XXXX07*#%*&; DHM24-XXXX07*#%*&
 Brand : innodisk
 Responsible Party : Innodisk Corporation
 Address : 5F.No.237, Sec. 1, Datong Rd., Xizhi Dist., New Taipei City 221,
 Taiwan (R.O.C.)

We, **International Standards Laboratory**, hereby certify that:

The device bearing the trade name and model specified above has been shown to comply with the applicable technical standards as indicated in the measurement report and was tested in accordance with the measurement procedures specified in European Council Directive- EMC Directive 2004/108/EC. The device was passed the test performed according to :



Standards:

EN 55022: 2010 and CISPR 22: 2008 (modified)
 EN 61000-3-2: 2006+A1:2009 +A2:2009 and IEC 61000-3-2: 2005+A1:2008 +A2:2009
 EN 61000-3-3: 2013 and IEC 61000-3-3: 2013
 EN 55024: 2010 and CISPR 24: 2010
 EN 61000-4-2: 2009 and IEC 61000-4-2: 2008
 EN 61000-4-3: 2006+A1: 2008 +A2: 2010 and
 IEC 61000-4-3:2006+A1: 2007+A2: 2010
 EN 61000-4-4: 2004 +A1:2010 and IEC 61000-4-4: 2004 +A1:2010

I attest to the accuracy of data and all measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

International Standards Laboratory

Jim Chu

Jim Chu / Director

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Certificate

Issue Date: May 14, 2014
 Ref. Report No. ISL-14LE187FB

Product Name : M.2 (S42) 3SE; M.2 (S42) 3ME; M.2 (S42) 3IE
 Model(s) : DEM24-XXXX07*#%※&; DHM24-XXXX07*#%※&
 Brand : innodisk
 Applicant : Innodisk Corporation
 Address : 5F.No.237, Sec. 1, Datong Rd., Xizhi Dist., New Taipei City 221,
 Taiwan (R.O.C.)

We, **International Standards Laboratory**, hereby certify that:

The device bearing the trade name and model specified above has been shown to comply with the applicable technical standards as indicated in the measurement report and was tested in accordance with the measurement procedures specified. (refer to Test Report if any modifications were made for compliance).



Standards:

FCC CFR Title 47 Part 15 Subpart B: 2012- Section 15.107 and 15.109
 ANSI C63.4-2009
 Industry Canada Interference-Causing Equipment Standard ICES-003 Issue 5: 2012

Class B

I attest to the accuracy of data and all measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

International Standards Laboratory


 Jim Chu / Director

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innodisk

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REACH Declaration of Conformity

Manufacturer Products: All Innodisk EM Flash and Dram products

1.宜鼎國際股份有限公司（以下稱本公司）特此保證此售予貴公司之產品，皆符合歐盟化學品法案(Registration, Evaluation and Authorization of Chemicals; REACH)之規定 (<http://www.echa.europa.eu/de/candidate-list-table> last updated: 16/12/2013)。所提供之產品包含：(1) 產品或產品所使用到的所有原物料；(2) 包裝材料；(3) 設計、生產及重工過程中所使用到的所有原物料。

We Innodisk Corporation hereby declare that our products are in compliance with the requirements according to the REACH Regulation

(<http://www.echa.europa.eu/de/candidate-list-table> last updated: 16/12/2013).

Products include : 1) Product and raw material used by the product : 2) Packaging material ; 3) Raw material used in the process of design, production and rework

2.本公司同意因本保證書或與本保證書相關事宜有所爭議時，雙方宜友好協商，達成協議。

InnoDisk Corporation agrees that both parties shall settle any dispute arising from or in connection with this Declaration of Conformity by friendly negotiations.

立 保 證 書 人 (Guarantor)

Company name 公司名稱：InnoDisk Corporation 宜鼎國際股份有限公司

Address：9F, No. 100, Sec.1 Xintai 5th Rd., Xizhi Dist., New Taipei City 221, Taiwan

Company Representative 公司代表人：Richard Lee 李鐘亮

Company Representative Title 公司代表人職稱：CEO 執行長

Date 日期：2014 / 03 / 18





宜鼎國際股份有限公司 Innodisk Corporation

Tel:(02)7703-3000 Fax:(02) 7703-3555 Internet: http://www.innodisk.com/

RoHS 自我宣告書 (RoHS Declaration of Conformity)

Manufacturer Product: All Innodisk EM Flash and Dram products

一、 宜鼎國際股份有限公司 (以下稱本公司) 特此保證售予貴公司之所有產品, 皆符合歐盟 2011/65/EU 關於 RoHS 之規範要求。

Innodisk Corporation declares that all products sold to the company, are complied with European Union RoHS Directive (2011/65/EU) requirement

二、 本公司同意因本保證書或與本保證書相關事宜有所爭議時, 雙方宜友好協商, 達成協議。

Innodisk Corporation agrees that both parties shall settle any dispute arising from or in connection with this Declaration of Conformity by friendly negotiations.

Name of hazardous substance	Limited of RoHS ppm (mg/kg)
Cd	< 100 ppm
Pb	< 1000 ppm
Hg	< 1000 ppm
Chromium VI (Cr+6)	< 1000 ppm
Polybromodiphenyl ether (PBDE)	< 1000 ppm
Polybrominated Biphenyls (PBB)	< 1000 ppm

立保證書人 (Guarantor)

Company name 公司名稱: Innodisk Corporation 宜鼎國際股份有限公司

Company Representative 公司代表人: Richard Lee 李鐘亮

Company Representative Title 公司代表人職稱: CEO 執行長

Date 日期: 2014 / 07 / 29

